

IGBT

SGR15N40L/SGU15N40L

General Description

Insulated Gate Bipolar Transistors (IGBTs) with a trench gate structure provide superior conduction and switching performance in comparison with transistors having a planar gate structure. They also have wide noise immunity. These devices are very suitable for strobe applications

Features

- High input impedance
- High peak current capability (130A)
- · Easy gate drive

Application

Strobe flash.







Absolute Maximum Ratings T_C = 25°C unless otherwise noted

| Symbol | Description | SGR / SGU15N40L | Units | |
|----------------------------------|---|-----------------|-------|--|
| V _{CES} | Collector - Emitter Voltage | 400 | V | |
| V _{GES} | Gate - Emitter Voltage | ± 6 | V | |
| I _{CM (1)} | Pulsed Collector Current | 130 | Α | |
| P _C | Maximum Power Dissipation @ T _C = 25°C | 45 | W | |
| P _C T _J | Operating Junction Temperature | -40 to +150 | °C | |
| T _{stq} | Storage Temperature Range | -40 to +150 | °C | |
| T _L | Maximum Lead Temp. for soldering purposes, 1/8" from case for 5 seconds | 300 | °C | |

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Тур. | Max. | Units |
|--------------------------|---|------|------|-------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case | | 3.0 | °C/W |
| R _{θJA} (D-PAK) | Thermal Resistance, Junction-to-Ambient (PCB Mount) (2) | | 50 | °C/W |
| R _{θJA} (I-PAK) | Thermal Resistance, Junction-to-Ambient | | 110 | °C/W |

Notes:

(2) Mounted on 1" square PCB (FR4 or G-10 Material)

| Symbol | ol Parameter Test Conditi | | Min. | Тур. | Max. | Units |
|---|--|--|------|------------------|-------|----------|
| Off Cha | racteristics | | | | | |
| BV _{CES} | Collector - Emitter Breakdown Voltage | $V_{GE} = 0V$, $I_C = 1mA$ | 450 | | | V |
| I _{CES} | Collector Cut-Off Current | $V_{CE} = V_{CES}, V_{GE} = 0V$ | | | 10 | uA |
| I _{GES} | G - E Leakage Voltage | $V_{GE} = V_{GES}, V_{CE} = 0V$ | | | ± 0.1 | uA |
| | racteristics | | | | | |
| $V_{GE(th)}$ | G - E Threshold Voltage | $I_C = 1 \text{mA}, V_{CE} = V_{GE}$ | 0.5 | 1.0 | 1.4 | V |
| V _{CE(sat)} | C - E Saturation Current | $I_C = 130A, V_{GE} = 4.5V$ | 2.0 | 4.5 | 8.0 | V |
| Dynami | c Characteristics | | | | | |
| • | | | | 3000 | | ηF |
| C _{ies} | Input Capacitance | V _{GE} = 0V, V _{CE} = 30V, | | 3000 | | pF |
| C _{ies} | Input Capacitance Output Capacitance | $V_{GE} = 0V, V_{CE} = 30V,$ f = 1MHz | | 45 | | pF |
| C _{ies} | Input Capacitance | 02 | | | | |
| C _{ies} C _{oes} C _{res} | Input Capacitance Output Capacitance | 02 | | 45 | | pF |
| C _{ies} C _{oes} C _{res} | Input Capacitance Output Capacitance Reverse Transfer Capacitance | f = 1MHz | | 45 | | pF |
| C _{ies} C _{oes} C _{res} Switchin | Input Capacitance Output Capacitance Reverse Transfer Capacitance ng Characteristics | f = 1MHz V _{CC} = 300V, I _C = 130A, | | 45 30 | | pF pF |
| C _{ies} C _{oes} C _{res} | Input Capacitance Output Capacitance Reverse Transfer Capacitance ng Characteristics Turn-On Delay Time | f = 1MHz | | 45 30 0.08 | | pF pF |

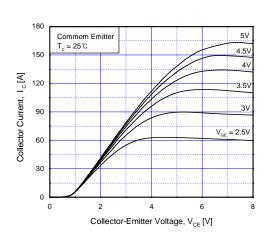


Fig 1. Typical Output Characteristics

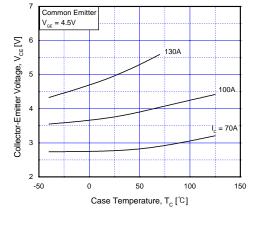


Fig 2. Saturation Voltage vs. Case Temperature at Variant Current Level

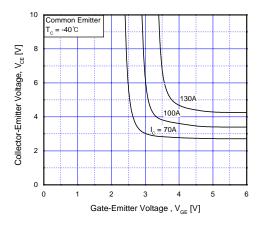


Fig 3. Saturation Voltage vs. V_{GE}

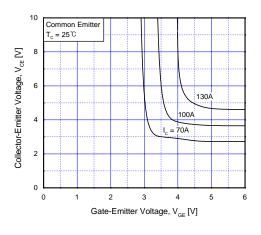


Fig 4. Saturation Voltage vs. V_{GE}

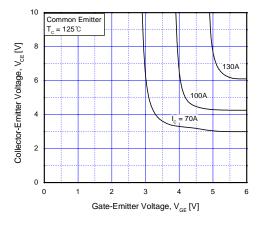


Fig 5. Saturation Voltage vs. V_{GE}

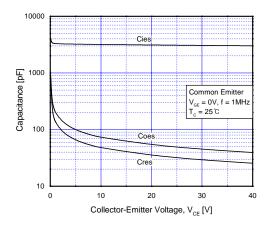
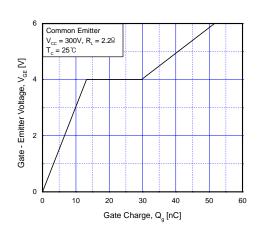


Fig 6. Capacitance Characteristics



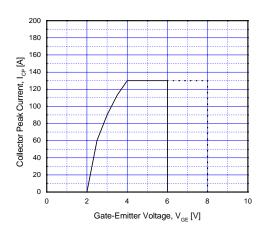
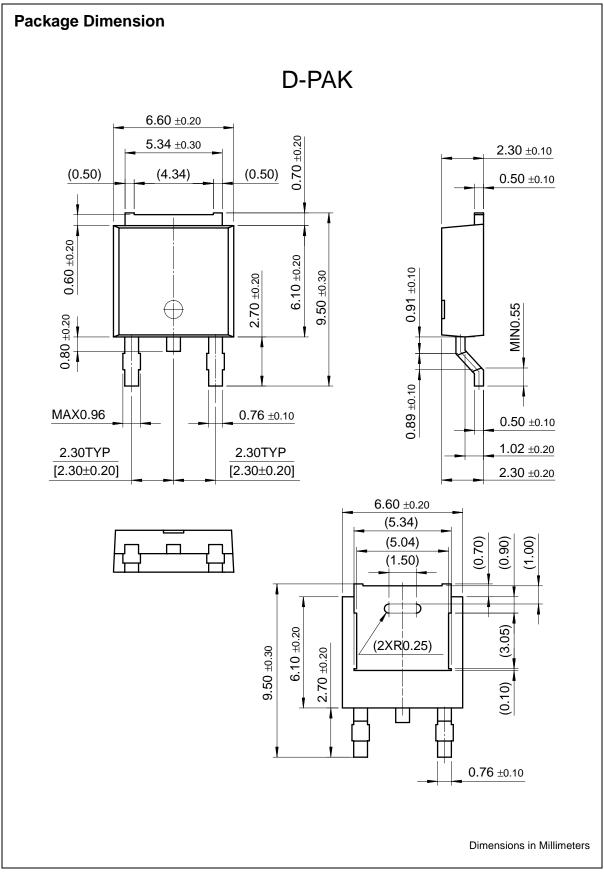
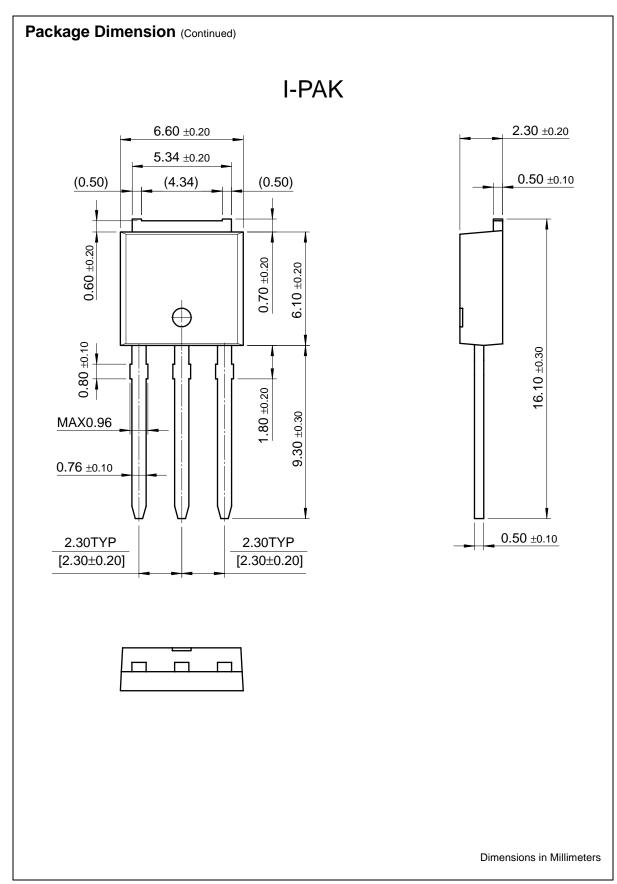


Fig 7. Gate Charge Characteristics

Fig 8. Collector Current Limit vs.

Gate - Emitter Voltage Limit





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Product status/pricing/packaging

| Product | Product status | Pricing* | Package type | Leads | Packing method |
|-------------|-----------------|----------|--------------|-------|----------------|
| SGU15N40LTU | Full Production | \$1.36 | TO-251(IPAK) | 3 | RAIL |

Product Folder - Fairchild P/N SGU15N40L - Discrete, IGBT

* 1,000 piece Budgetary Pricing

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Application notes

AN-9006: AN-9006 IGBT Application Note for Camera Strobe (146 K)
Jul 19, 2002

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Product Product status Pricing* Package type

Product status/pricing/packaging

| Product | Product status | Pricing* | Package type | Leads | Packing method |
|-------------|-----------------|----------|--------------|-------|----------------|
| SGR15N40LTF | Full Production | \$1.36 | TO-252(DPAK) | 2 | TAPE REEL |

| SGR15N40LTM | Full Production | \$1.36 | TO-252(DPAK) | 2 | TAPE REEL |
|-------------|-----------------|--------|--------------|---|-----------|

^{* 1,000} piece Budgetary Pricing

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Application notes

<u>AN-9006: AN-9006 IGBT Application Note for Camera Strobe</u> (146 K) Jul 19, 2002

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